



Rev.01 - 17 November 2023

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 plastic package intended for use in applications requiring high bidirectional blocking voltage capability, high current inrush capability and high thermal cycling performance

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- High voltage capacity
- Very high current surge capability

3. Applications

- DC Motor control
- Power converter
- Lighting and temperature control
- Softstart AC motor control
- AC power control
- Solid State Relay (SSR)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
V _{drm}	repetitive peak off-state voltage				1200		V
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 132 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u>		47		A	
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>		350		A	
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms			385		А
T _j	junction temperature			150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V_{D} = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 7		-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	80	mA
V _T	on-state voltage	$I_{T} = 30 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$		-	-	1.30	V
Dynamic	characteristics						
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		1000	-	-	V/µs

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode		A H K G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information							
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
BT153-1200T	TO220	BT153-1200TQ	Tube	50	SOT78	13-Jun-2008	

7. Marking

Table 4. Marking codes

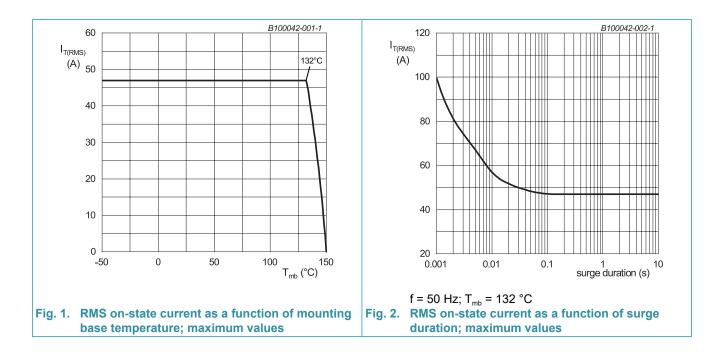
Type number	Marking codes
BT153-1200T	BT153 1200T

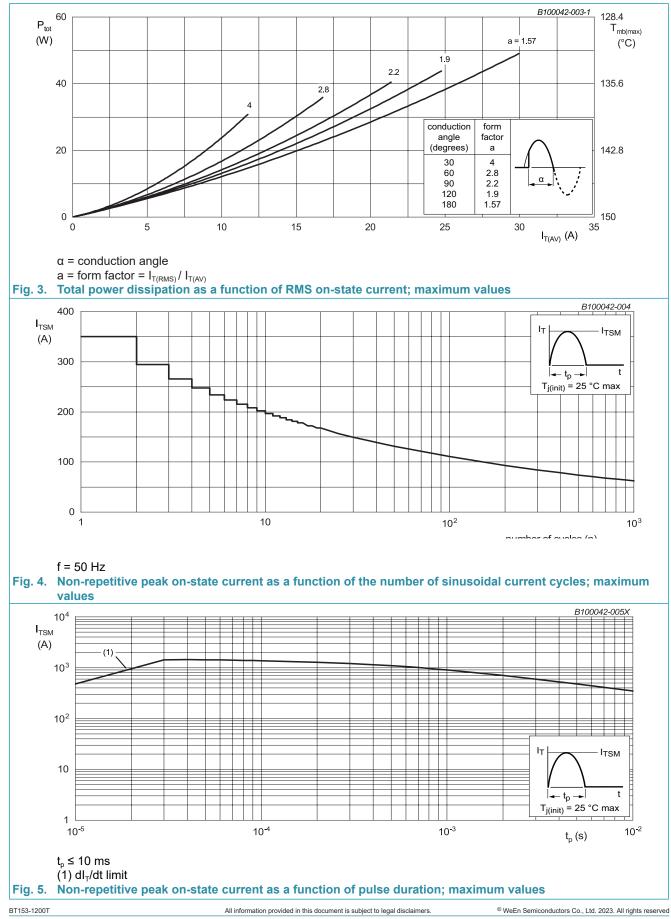
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

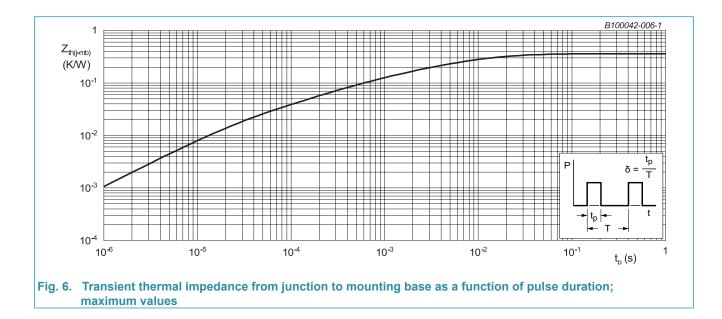
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			1200	V
V_{RRM}	repetitive peak reverse voltage			1200	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 132 \text{ °C}$;		30	А
$\mathbf{I}_{\mathrm{T(RMS)}}$	RMS on-state current	half sine wave; $T_{mb} \le 132 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3		47	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5		350	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		385	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse		612.5	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 100 mA		150	A/µs
I _{GM}	peak gate current			5	А
V_{GM}	peak gate voltage			5	V
P_{GM}	peak gate power	T _{j(init)} = 25 °C; t _p = 20 μs		20	W
$P_{G(AV)}$	average gate power	over any 20 ms period		0.5	W
T _{stg}	storage temperature			-40 to 150	°C
Tj	junction temperature			150	°C





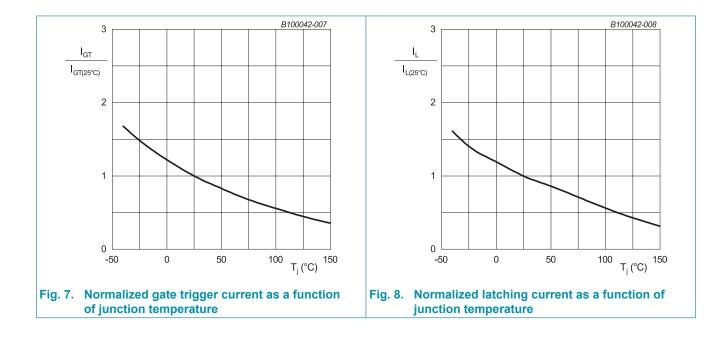
9. Thermal characteristics

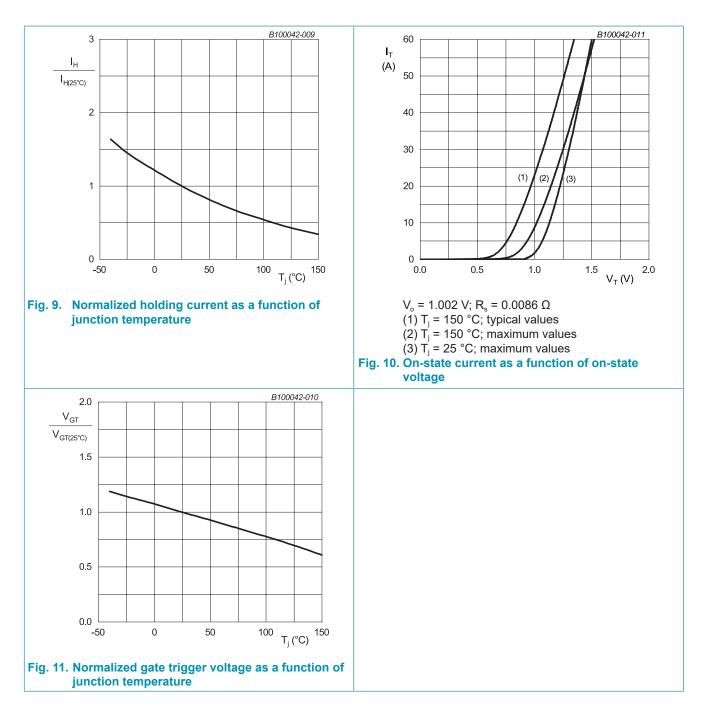
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>		-	-	0.36	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W



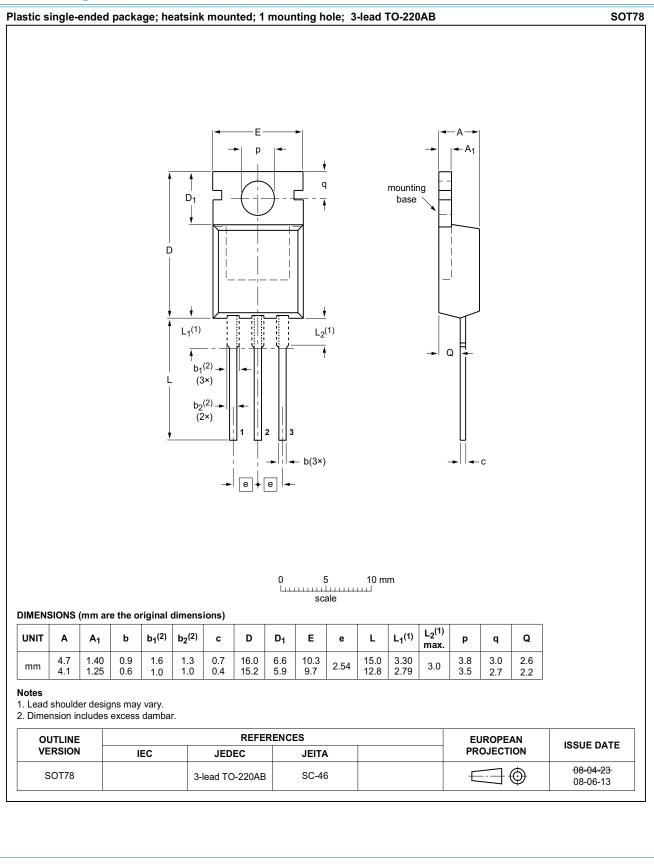
10. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 7		-	-	50	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 8		-	-	100	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	80	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u>		-	-	1.30	V
V _{gt}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>		-	0.75	1.0	V
		V _D = 1200 V; I _T = 0.1 A; T _j = 150 °C		0.20	0.45	-	V
I _D	off-state current	V _D = 1200 V; T _j = 25 °C		-	-	30	μA
		V _D = 1200 V; T _j = 125 °C		-	-	2	mA
I _R	reverse current	V _D = 1200 V; T _j = 25 °C		-	-	30	μA
		V _D = 1200 V; T _j = 125 °C		-	-	2	mA
Dynamic	characteristics	-		1			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		1000	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 30 \text{ A}; V_D = 800 \text{ V}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu\text{s}; T_j = 25 ^{\circ}\text{C}$		-	2	-	μs
t _q	commutated turn-off time	$V_{DM} = 804 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{TM} = 30 \text{ A};$ $V_{R} = 25 \text{ V}; (\text{d}_{T}/\text{d}_{t})\text{M} = 30 \text{ A}/\text{\mu s};$ $\text{dV}_{D}/\text{dt} = 50 \text{ V}/\text{\mu s}; (\text{V}_{DM} = 67\% \text{ of } \text{V}_{DRM})$		-	70	-	μs





11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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13. Contents

1	General description	1
2.	Features and benefits	.1
3.	Applications	.1
4.	Quick reference data	.1
5.	Pinning information	.2
6.	Ordering information	.2
7.	Marking	.2
8.	Limiting values	.3
9.	Thermal characteristics	.5
10	Characteristics	.6
11.	Package outline	.8
12	. Legal information	.9
13.	. Contents	11

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